




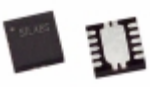
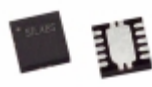

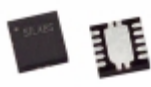
	<p><b>SI3460BDV-T1-E3</b></p>
	<p><b>Hersteller-Teilenummer:</b> SI3460BDV-T1-E3</p> <p><b>Hersteller / Marke:</b> Vishay / Siliconix</p> <p><b>Teil der Beschreibung:</b> MOSFET N-CH 20V 8A 6-TSOP</p> <p><b>Datenblätter:</b>  <a href="#">SI3460BDV-T1-E3.pdf</a></p> <p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p> <p><b>Lagerzustand:</b> New original, 58074 pcs Stock Available.</p> <p><b>Liefern von:</b> Hong Kong</p> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

**Spezifikationen**

Teilenummer	SI3460BDV-T1-E3
Hersteller	Vishay / Siliconix
Beschreibung	MOSFET N-CH 20V 8A 6-TSOP
Kategorie	<a href="#">Diskrete Halbleiterprodukte</a> > <a href="#">Transistoren-FETs</a> ,
Teilstatus	58074 pcs Stock
Serie	TrenchFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	SOT-23-6 Thin, TSOT-23-6
Supplier Device-Gehäuse	6-TSOP
Verlustleistung (max)	2W (Ta), 3.5W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	20V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	8A (Tc)
Rds On (Max) @ Id, Vgs	27 mOhm @ 5.1A, 4.5V
VGS (th) (Max) @ Id	1V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	24nC @ 8V
Eingabekapazität (Ciss) (Max) @ Vds	860pF @ 10V
Antriebsspannung (Max Rds On, Min Rds On)	1.8V, 4.5V
Vgs (Max)	±8V
Verpackung	Tape & Reel (TR)



































SI3460BDV-T1-E3 ist neu im Original, Suche SI3460BDV-T1-E3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI3460BDV-T1-E3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SI3460BDV-T1-E3: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

 <p><b>SI3460-EVB</b> Energy Micro (Silicon Labs) BOARD EVAL POE FOR SI3460</p>	 <p><b>SI3460BDV-T1-E3</b> Electro-Films (EFI) / Vishay MOSFET N-CH 20V 8A 6-TSOP</p>	 <p><b>SI3460DDV</b> Vishay SI3460DDV Vishay</p>	 <p><b>SI3460DDV-T1-GE3</b> Vishay / Siliconix MOSFET N-CH 20V 7.9A 6-TSOP</p>
 <p><b>SI3460-E02-GMR</b> Energy Micro (Silicon Labs) IC POWER MANAGEMENT CTRLR 11VQFN</p>	 <p><b>SI3460-E03-GM</b> Energy Micro (Silicon Labs) IC POWER MANAGEMENT CTRLR 11VQFN</p>	 <p><b>SI3460BDV-T1-GE3</b> Vishay / Siliconix MOSFET N-CH 20V 8A 6-TSOP</p>	 <p><b>SI3460-E03-GMR</b> Energy Micro (Silicon Labs) IC POWER MANAGEMENT CTRLR 11VQFN</p>

**heiße Teile**

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|  SI3457CDV-T1-GE3 |  SI3457CDV-T1-GE3 |  SI3457DV         |  SI3457DV         |  SI3457DV-T1      |
|  SI3457DV-T1-E3   |  SI3457DV-T1-GE3  |  SI3457DV-TI-E3   |  SI3458BDV-T1-E3  |  SI3458BDV-T1-E3  |
|  SI3458BDV-T1-GE3 |  SI3458BDV-T1-GE3 |  SI3458DV-T1-E3   |  SI3458DV-T1-E3   |  SI3458DV-T1-GE3  |
|  SI3459BDV-T1-E   |  SI3459BDV-T1-E3  |  SI3459BDV-T1-E3  |  SI3459BDV-T1-GE3 |  SI3459BDV-T1-GE3 |
|  SI3459DV-T1-E3   |  SI3459DV-T1-E3   |  SI3459DV-T1-GE3  |  SI3460-E02-GMR   |  SI3460-E03-GMR   |
|  SI3460BDV-T1-E3  |  SI3460BDV-T1-GE3 |  SI3460BDV-T1-GE3 |  SI3460DDV        |  SI3460DDV-T1-GE3 |
|  SI3460DDV-T1-GE3 |  SI3460DV         |  SI3460DV-T1      |  SI3460DV-T1-E3   |  SI3460DV-T1-E3   |
|  SI3460DV-T1-GE3  |  SI3460DV-T1-GE3  |  SI3461DV-T1-E3   |  SI3461DVT1-GE3   |  SI3464DV         |
|  SI3464DV-T1-GE3  |  SI3464DV-T1-GE3  |  SI3465DV-T1-E3   |  SI3465DV-T1-E3   |  SI3465DV-T1-GE3  |
|  SI3465DV-T1-GE3  |  SI3467DV         |  SI3467DV-T1-E3   |  SI3467DV-T1-E3   |  SI3467DV-T1-GE3  |

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